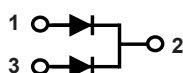
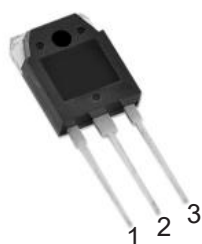


Epitaxial Superfast Recovery Rectifier

TO-3P
MURE2020WB



Features

- Low forward voltage drop
- Low leakage current
- High current capability
- Super fast switching speed
- High forward surge capability
- High reliability

Mechanical Data

- Epoxy: UL 94V-O rate flame retardant
- Lead: lead solderable per MIL-STD-202, method 208 guaranteed
- Mounting position: Any

Parameter	Symbols	MURE2020WB		Units
Maximum Repetitive Peak Reverse Voltage	VRRM	200		V
Maximum RMS voltage	VRMS	140		V
Maximum DC Blocking Voltage	VDC	200		V
Maximum Average Forward Rectified Current	I(AV)	20.0		A
Reverse Recovery Time. IF=0.5A, IR=1A, IRR=0.25A	Trr	35		ns
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	IFSM	220		A
Instantaneous Forward Voltage per Diode@TA=25 °C	VF	Typ	Max	V
		IF=3A	0.75	
		IF=10A	0.89	
Maximum DC Reverse Current @TA=25 °C at Rated DC Blocking Voltage @TA=125 °C	IR	10 500		μA
Operating and Storage Temperature Range	Tj, Tstg	-55 ~ +150		°C
Typical thermal resistance (Note 1)	RthJC	1.5		°C/W

Note: 1. Thermal resistance junction to case, lead and ambient in accordance with JESD-51.
Unit mounted on glass-epoxy substrate with 1oz/ft² 20x20 mm copper pad per pin with heatsink

RATINGS AND CHARACTERISTICS CURVES (TA = 25 °C unless otherwise noted)

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

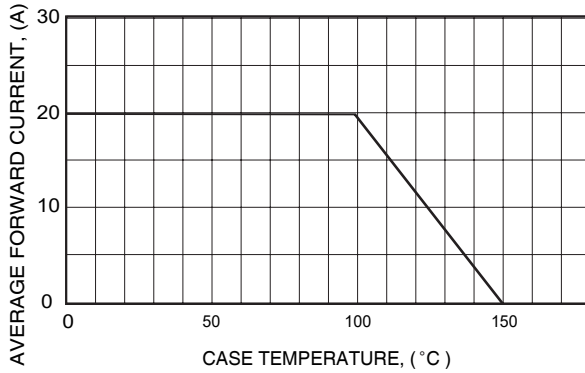


FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

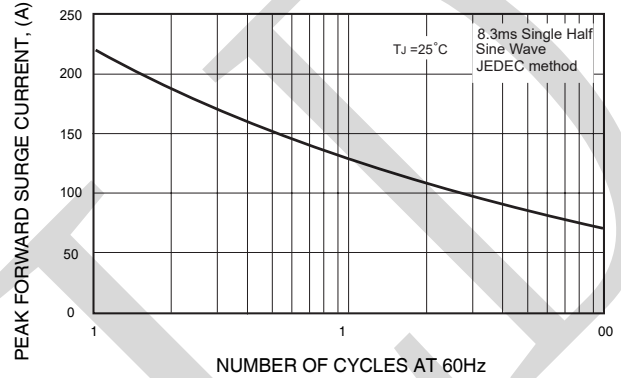


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

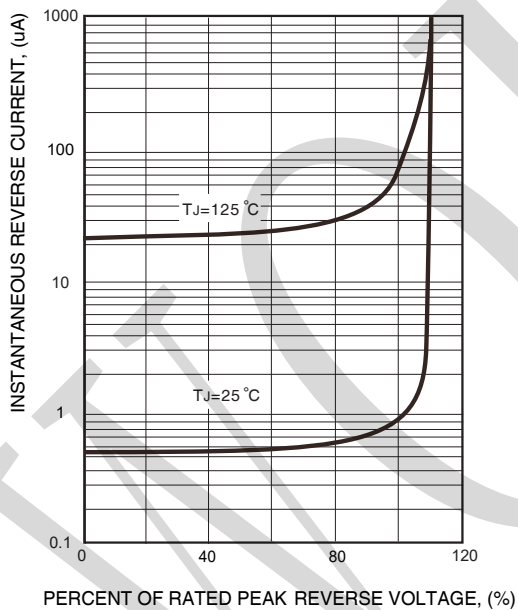
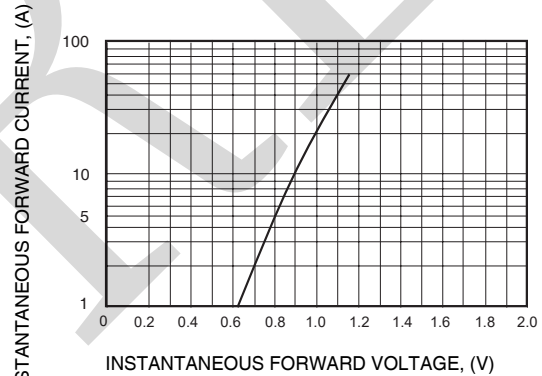


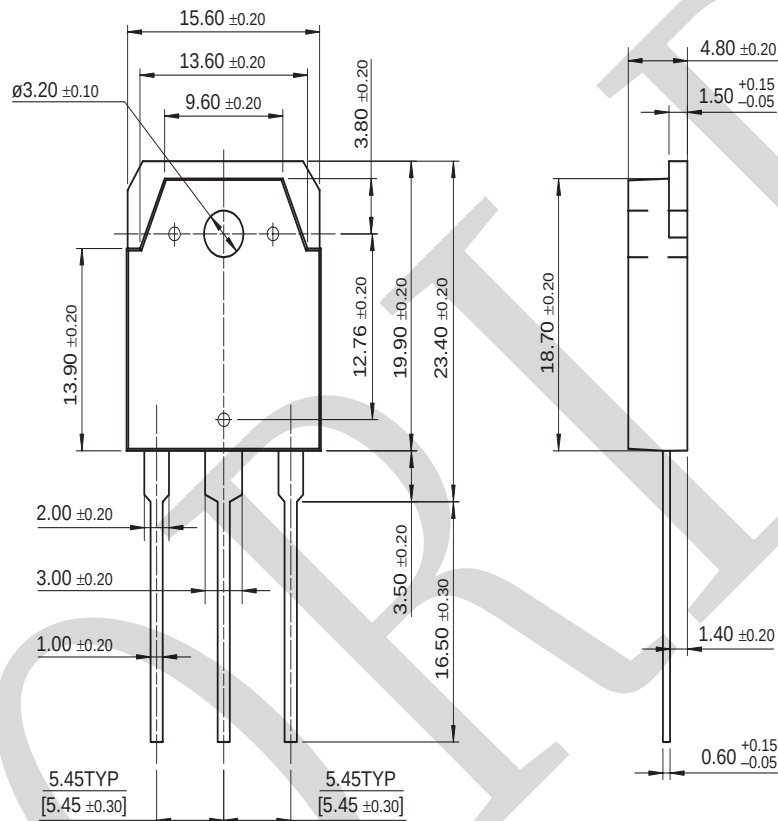
FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



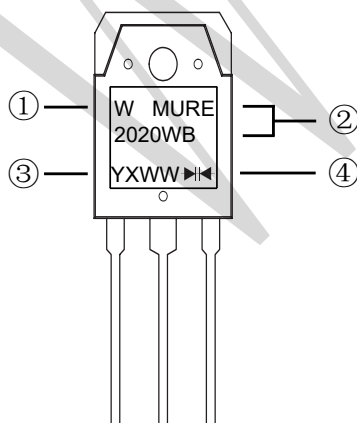
PACKAGE OUTLINE DIMENSIONS

Note:unit: mm

TO-3P



Marking Information



- ① W : Company's trademark
- ② Product model : MURE2020WB

③ PDC information :

Y X WW

WW:Week code(01 to 53)

X:Internal identification code

Y:Year code(ex:0=2020)

④ Double wafer